L Number	Hits	Search Text	DB	Time stamp
1	24	nakamura.in. and modul\$5 near3 dop\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/04 10:05
3	5	ratio near10 superlattice same (gan or gallium near2 nitride)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/04 10:08
2	86	thick\$6 near10 superlattice same (gan or gallium near2 nitride)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/04
74	164	(hirayama near2 hideki or aoyagi near2 yoshinobu or hirata near2 akira).in.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/04
75	2	((hirayama near2 hideki or aoyagi near2 yoshinobu or hirata near2 akira).in.) and superlattice	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/03/04 14:27
-	395	buffer same superlattice and 257/\$4.ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/12/03 16:32
-	106	buffer.clm. and superlattice.clm. and 257/\$4.ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/12/03
-	52	buffer near2 (dop\$4 or impurit\$4) near20 nm	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/23 14:00
_	8	<pre>superlattice near2 (dop\$4 or impurit\$4) near20 nm</pre>	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/23 14:28
-	620	superlattice near20 nm	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/23 14:28
-	38	superlattice near20 nm near10 (nitride or gan or algan)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/23 14:43
_	2	superlattice near20 (nitride or gan or algan) near10 (thick\$6) near5 (vary\$4 or differ\$5)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/23 14:48
-	80	superlattice near20 (nitride or gan or algan) near10 (thick\$6)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/23 1 4: 48
	2	"20030168653"	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/03/02 17:06

Search History

3/4/04 2:28:47 PM

<u> </u>	4	(#5077565# #5075052#)	T	
-	4	("5977565" "5875052").pn.	USPAT;	2004/03/02
ľ	ŀ		US-PGPUB;	17:17
			EPO; JPO;	
			DERWENT;	
ŀ		60.66055	IBM_TDB	
_	2	6266355.pn.	USPAT;	2004/03/02
			US-PGPUB;	17:20
			EPO; JPO;	
			DERWENT;	
1			IBM TDB	
-	2	6586774.pn.	USPAT;	2004/03/02
			US-PGPUB;	17:20
	l 4		EPO; JPO;	
	*		DERWENT;	1
	1 - 8		IBM TDB	1
-	2976	modul\$5 near2 dop\$5	USPAT;	2004/03/03
1	Ř.	_	US-PGPUB;	17:28
	1 <u>1</u>		EPO; JPO;	
	, s		DERWENT;	
		,	IBM TDB	į i
_	253	modul\$5 near2 dop\$5 same superlattice	USPAT;	2004/03/03
		and the state of t	US-PGPUB;	17:28
			EPO; JPO;	17.20
			DERWENT;	
			IBM TDB]
_	78	modul\$5 near2 dop\$5 same superlattice	USPAT;	2004/02/04
	'	same (gan or gallium adj nitride)	1	2004/03/04
		Same (gan of gallium ad) nitride/	US-PGPUB;	13:47
			EPO; JPO;	l
			DERWENT;	
l i	10	modulés manna danés	IBM_TDB	
-	10		USPAT;	2004/03/03
		same (gan or gallium adj nitride) same nm	US-PGPUB;	17:32
	-		EPO; JPO;	
]			DERWENT;	
_	4.4	10 (3)	IBM_TDB	
] ⁻	44		USPAT;	2004/03/03
		thick	US-PGPUB;	17:40
			EPO; JPO;	
			DERWENT;	
	_		IBM_TDB]
_	4	superlattice near10 thickness near10	USPAT;	2004/03/03
		thick same (gan or gallium adj nitride)	US-PGPUB;	17:42
			EPO; JPO;	İ
			DERWENT;	
	İ		IBM TDB	
-	26	superlattice near10 thickness near10 nm	USPAT;	2004/03/04
	1	same (gan or gallium adj nitride)	US-PGPUB;	10:03
			EPO; JPO;	
]			DERWENT;	ļ
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